

Evidence of ferromagnetic quantum phase transition in $\text{Ba}_{1-x}\text{Sr}_x\text{VS}_3$

Andrea Gauzzi^{1,*}, Neven Barišić², Francesca Licci¹, Gianluca Calestani³,

Fulvio Bolzoni¹, Patrik Fazekas⁴, Edi Gilioli¹, and László Forró²

¹IMEM-CNR, Area delle Scienze, 43010 Parma, Italy

²Institut de Physique de la Matière Complexe, EPFL, CH-1015 Lausanne, Switzerland

³Dipartimento di Chimica, Università di Parma, Area delle Scienze, 43100 Parma, Italy

⁴Research Institute for Solid State Physics and Optics, P.O. Box 49, H-1525 Budapest, Hungary

(Dated: February 6, 2008)

Resistivity under pressure and magnetization measurements on $\text{Ba}_{1-x}\text{Sr}_x\text{VS}_3$ single crystals with $0 \leq x \leq 0.18$ and no sulphur deficiency show an abrupt onset of ferromagnetic (FM) order at a critical value $x=0.07$, concomitant to a change of the magnetic properties at the metal-insulator transition (MIT) and to a collapse of the unit cell at ambient temperature. A reduction of the MIT temperature to 50 K upon x that scales as the V-S distance is also observed. This gives evidence of a chemical pressure induced quantum phase transition that stabilizes the incipient FM order of BaVS_3 . The $0.07 < x$ results suggest a coexistence of FM and metallic phases at larger x .

PACS numbers: 71.30.+h, 71.27.+a, 75.50.-y

Keywords:

The hexagonal perovskite $\text{BaVS}_{3-\delta}$ [1] displays a manifold of magnetic, transport and structural properties driven by $3d(\text{V}^{4+})$ electron correlations. In the high temperature metallic phase, it consists of hexagonal closed packed chains of face-sharing VS_6 octahedra. The MI transition $T_{MI}=69$ K is preceded by a zigzag of the chains at 240 K leading to an orthorhombic structure [3]. T_{MI} decreases under pressure and the insulating phase is suppressed for $P > 2$ GPa [2]. In stoichiometric compounds ($\delta=0$), the ambient pressure transition is concomitant to an AF-like cusp of the magnetic susceptibility, χ [1], and to a $2 \times c$ superstructure along the chains [4, 5]. A neutron scattering study [6] reported a long range AF-like order in the ab -plane and an intrachain ferromagnetic (FM) one at $T_X=30$ K, related to the cusp. Assuming a large number of degenerate configurations of singlet pairs with different orbital symmetry in the triangular plane, a picture of spin-orbital liquid was proposed [6, 7]. A latent FM instability is apparent from the positive Weiss constant in the metallic phase and the FM behavior of sulphur-deficient samples [8]. In agreement with these experiments, *ab initio* calculations [9, 10] predict a dominant FM coupling along c and a comparatively weak AF one in the ab -plane, thus suggesting a ground state of FM chains with a nearly frustrated AF interchain coupling.

The origin of the MI transition and its relation with the magnetic and orbital orderings remain controversial. Overlapping wide and narrow d -bands were recently observed by ARPES [11]. A simple tight-binding model explaining the physical properties at the MI transition includes a broad A_{1g} band arising

from the direct overlap of $3d_{z^2}$ orbitals along the c -axis, and a doubly degenerate E_g narrow band created by the small $\text{V}(3d)\text{-S}(3p)$ hybridization [8, 15]. The width and relative occupancy of the bands remain to be determined experimentally. An X-ray diffraction study [5] suggests a nearly equal filling of the A_{1g} and E_g bands. A tuning mechanism for the occupancy of these two bands was recently proposed [12].

In this letter, we study the effects of chemical pressure on the magnetic, transport and structural properties of the system. At a critical value, $x=0.07$, an abrupt onset of FM order is found concomitant to a disappearance of the AF-like cusp at the MI transition and to a collapse of the unit cell at room temperature. A progressive reduction of T_{MI} and smearing of the AF-like cusp with increasing x is also observed. The observation of a quantum phase transition (QPT) from a non-FM to a FM low-temperature state shows that the incipient FM order in the parent compound is stabilized by chemical pressure. The second result suggests a coexistence of FM and metallic phases at high pressure [15]. We discuss the possibility that the two phases coincide in the absence of disorder. We argue that the collapse of the unit cell is due to a sudden redistribution of electron charge between the relevant A_{1g} and E_{g1} bands.

A series of $\text{Ba}_{1-x}\text{Sr}_x\text{VS}_3$ single crystals with $x = 0.032, 0.053, 0.064, 0.068, 0.097, 0.126$, and 0.183 were grown as described elsewhere using a solid state method [13]. Attempts to grow crystals with larger x values were unsuccessful. At $x = 0.183$, diffraction data indicate a significant amount of disorder and stacking faults, thus $x \approx 0.18$ appears to be close to

the solubility limit. The needle-shaped crystals, 0.1 - 0.3 mm long, are aligned along the c -axis. The room temperature crystal structure, the Sr/Ba composition and the sulfur content were determined using X-ray diffraction. Within the experimental resolution, the crystal symmetry remains $P6_3/mmc$ for all x values, as in the unsubstituted compound. The structural refinement indicates no sulfur deficiency for any x with a statistical uncertainty $\delta \pm 0.05$ or better. As a further check of the sulfur stoichiometry, a post-sulfurisation treatment in evacuated quartz ampoules at 450°C for 3 days is found to affect neither the structural nor the physical properties. Thus, the results reported are exclusively ascribed to the Sr-induced chemical pressure.

The crystals were investigated by means of dc electrical resistivity under pressure, $\rho(T, P)$, up to 2 GPa, and dc magnetization, $M(T)$. ρ was measured in a four contact bar configuration in self-clamping pressure cells filled with kerosene as pressurizing agent. Since the needle-shaped crystals grow along the c -axis, the c -axis resistivity, ρ_c , was measured. M was measured in the zero-field and field-cooling (ZFC, FC) modes at 100 oersted using a commercial RF SQUID magnetometer. Because of the small crystal size, the sample weight could not be determined. Yet, the sample sizes are comparable and the relative magnitude of M is significant.

A set of $\rho_c(T, P)$ curves is shown in Fig. 1 for $x=0.126$. Similarly to the case of the unsubstituted compound [2] ($x=0$), a progressive reduction of T_{MI} with increasing pressure is found. T_{MI} was estimated as the peak of the $d\ln\rho/d(1/T)$ vs. T plot [2]. The effect of T_{MI} reduction with increasing x and with increasing pressure is apparent in the $P - T$ diagram of Fig. 2 that summarizes the ρ data. For $x \approx 0.12$, the insulating state is suppressed at ≈ 1 GPa, i.e. half of the value for the unsubstituted compound [2]. By comparing the $\rho_c(T, P)$ curves in the inset of Fig. 1, one notes that the T_{MI} reduction is accompanied by an increase of the slope, $d\rho_c/dT$, with increasing pressure. This trend is common to all samples and indicates a pressure-induced enhancement of the metallic properties, although the system remains a bad metal. By comparing the $\rho(T)$ curves for different x , we observed that the residual resistivity increases with increasing x [14]. This trend indicates that the Sr-substitution creates a substantial amount of disorder, in agreement with diffraction data.

The T_{MI} reduction is correlated with the Sr-induced structural changes of the a - and c -axis as shown in Fig. 3. One notes that the smaller Sr ion induces a shrinking of the unit cell, as expected. Two

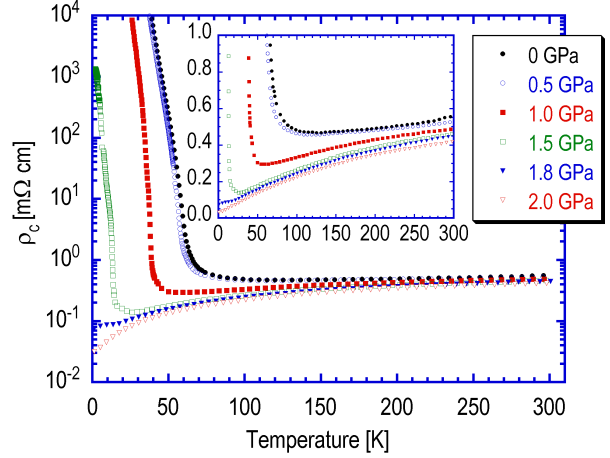


FIG. 1: c -axis resistivity curves as a function of temperature and pressure for $x=0.126$. One notes the steady reduction of the metal-insulator transition temperature T_{MI} , as pressure increases.

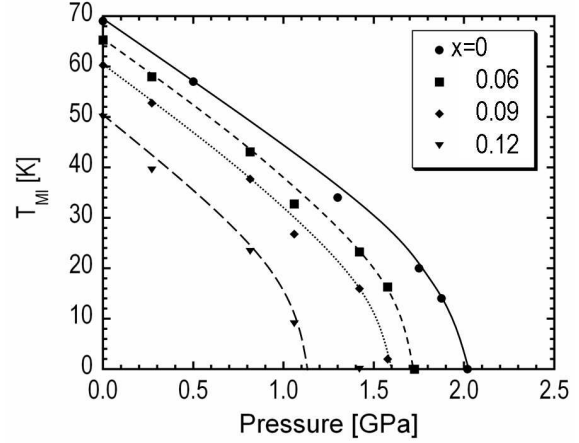


FIG. 2: Progressive reduction of T_{MI} upon x from the full set of the $\rho_c(T, P)$ data. The $x = 0$ data are taken from ref. [2]. Lines are a guide to the eye.

features are though unusual: 1) at low substitution levels, $x \lesssim 0.05$, the shrinking is negligible; 2) at higher x values, the shrinking is large and occurs suddenly, first along the c -axis at $x \approx 0.07$ and then in the ab -plane at $x \approx 0.10$. The latter shrinking is largest and corresponds to a collapse of the chains of VS_6 octahedra one against the other. The c -axis increase at $x \gtrsim 0.10$ is consistent with the previous observation of disorder and stacking faults in this x range. In spite of this, the cell volume continues to decrease with x , for the shrinking of the a -axis dominates. The sudden drop of the a - and c -axis at $x \approx 0.07$ appears to be a

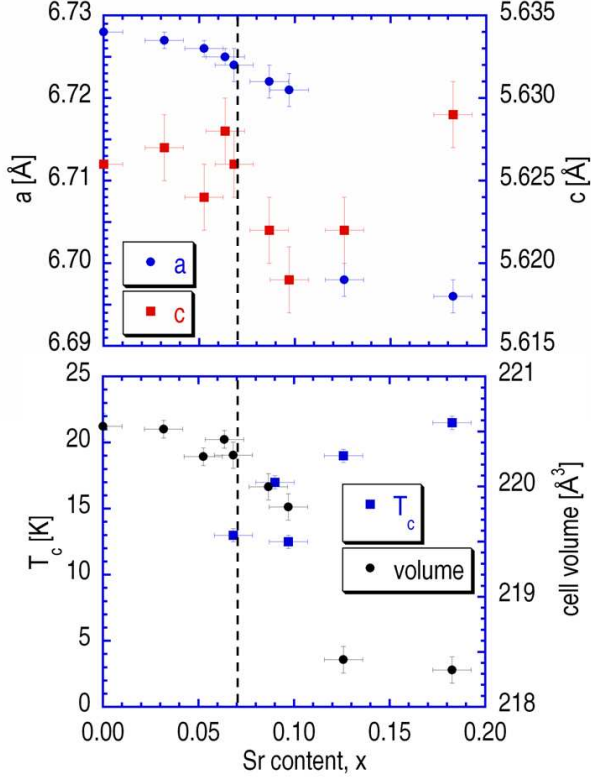


FIG. 3: Top panel: a - and c -axis variations of the hexagonal unit cell of $\text{Ba}_{1-x}\text{Sr}_x\text{VS}_3$ with x . Note the drop of the c -axis at $x \approx 0.07$ and the progressive reduction of the a -axis followed by a large drop at $x \approx 0.10$. Error bars are standard deviations of the data refinement. Bottom panel: correlation between cell volume reduction and Curie temperature, T_C , and x . The vertical line at $x = 0.07$ marks the onset of the cell volume drop and of the FM order.

room temperature signature of a phase transition at low temperature, as discussed below.

By analyzing the structural data, the V-S bond distance in the VS_6 octahedra is found to be the only parameter that scales with T_{MI} . A linear regression of the T_{MI} vs. V-S data enables to predict that the M-I transition would be suppressed for V-S=2.372 Å. This result is in agreement with the observation of T_{MI} reduction upon hydrostatic pressure [2]. One concludes that the volume reduction induced by either chemical or hydrostatic pressure stabilizes the metallic state. The T_{MI} reduction observed in our $\text{Ba}_{1-x}\text{Sr}_x\text{VS}_3$ samples is correlated to the magnetization data as follows. In Fig. 4 we report a selection of $M(T)$ curves for three different x values in the $x=0.06$ -0.10 region, that turns out to be critical, as shown below. For $x \lesssim 0.07$, no significant differ-

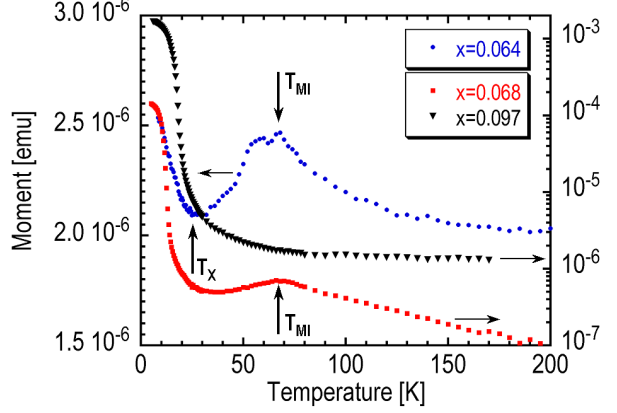


FIG. 4: ZFC magnetization for three different x -values showing the disappearance of the AF-like cusp at T_{MI} and of the upturn at T_X concomitant to the onset of FM order at $x \approx 0.07$. Note the different vertical scales.

ence between ZFC and FC curves is observed, so only the former case is considered. The AF-like cusp of χ characteristic of the unsubstituted compound [3, 8] remains visible at T_{MI} , although smeared by disorder. By taking the cusp as the magnetic signature of T_{MI} , the T_{MI} vs. x magnetization data are found to coincide with the resistivity ones discussed before. The two data sets are reported in Fig. 5 and show the same monotonic decrease of T_{MI} with x . Also the upturn of the $M(T)$ curve at T_X characteristic of the unsubstituted compound [7] remains visible for $x \lesssim 0.07$. Contrary to the case of the AF-like cusp, the temperature of the upturn hardly varies with x but also the upturn becomes smeared with x . At $x_{cr} = 0.07$, both the cusp and the upturn disappear and a FM response suddenly appears with $T_C=12$ K, determined as the maximum of the derivative of the $M(T)$ curve.

The above observations lead to conclude that the MI transition is not necessarily associated with the magnetic correlations. This contrasts to the transition at T_x [14, 15], characterized by a FM order along the chains, in agreement with neutron diffraction data [6] and with the FM above x_{cr} presented in this letter. The analysis of several crystals with $x \approx 0.07$ confirms the sudden character of the onset of the FM order and its coincidence with the disappearance of the AF-like cusp of χ and an equally sudden drop of cell volume. In the bottom panel of Fig. 3, we show the correlation between volume reduction and onset of FM order upon x . At $x_{cr} > 0.07$, T_C slowly increases and equals 22 K at $x \approx 0.18$.

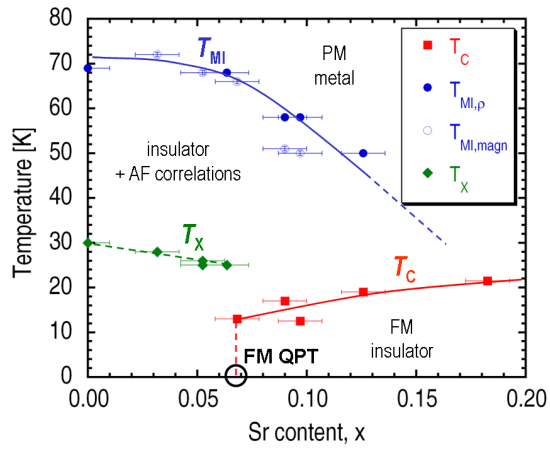


FIG. 5: Electronic phase diagram of $\text{Ba}_{1-x}\text{Sr}_x\text{VS}_3$ at ambient pressure. Full and open circles indicate the T_{MI} values determined from, respectively, resistivity and magnetization data. The smearing of the AF-like cusp at T_X upon x discussed in the text is indicated as a broken line. The vertical line at $x=0.07$ marks the abrupt onset of ferromagnetic (FM) order. Lines are a guide to the eye.

Fig. 5 summarizes all data discussed above and serves as electronic phase diagram. The AF-like borderline is derived from the estimation of T_X as upturn of the magnetization. The upturn being increasingly smeared with x , as it is apparent from Fig. 4, we believe that a long range order in the ab-plane no longer exists in the substituted compounds near x_{cr} . Thus, the sudden stabilization of the FM order at x_{cr} and at low temperature is a quantum phase transition that distinguishes the FM order from a phase with AF-like correlations in the ab-plane that become weaker with increasing x . The drop of cell volume at x_{cr} appears as a structural signature of the electronic instability at room temperature.

In conclusion, we studied the effects of chemical pressure on the MI and AF-FM competitions in the BaVS_3 system on a series of $\text{Ba}_{1-x}\text{Sr}_x\text{VS}_3$ single crystals. The data of resistivity under pressure show that the Sr-induced chemical pressure stabilizes the metallic phase. Consequently, by increasing x from 0 to 0.12 the T_{MI} is reduced from 69K down to 50 and the critical pressure for the suppression of the MI transition at 0K decreases from 2 to 1 GPa. At $x_{cr} = 0.07$, we found a sudden shrinking of the unit cell concomitant to the disappearance of the AF-like susceptibility cusp at T_{MI} and to the appearance of a full FM order at low temperatures. This transition confirms the small energy difference between the AF-like and FM

orderings of the V^{4+} ions calculated *ab initio* [10]. By extrapolating the T_{MI} vs. V-S bond data, a metallic state at 0 K is predicted for a distance of 2.372 Å. The present data suggest that, at higher x or pressure, the FM and metallic state should coexist [15], as in BaVSe_3 [14, 16]. The question arises as to the mechanism leading to the FM order in our case. The absence of sulphur deficiency rules out the Hund mechanism proposed for sulphur-deficient compounds [17]. The Sr/Ba chemical disorder would favor a double-exchange mechanism, thus one should study samples without disorder. As disorder tends to stabilize the insulating state, the reduction of T_{MI} reported here is expected to be even stronger in the absence of disorder. The MI quantum phase transition predicted at $x \approx 0.15$ from the data of Fig. 5 would then approach the FM QPT at $x = 0.07$. In the extreme case, the two points may merge, which would be important from a fundamental point of view.

The authors thank M. Marezio for useful discussions and T. Besagni for technical assistance and acknowledge financial support provided by the *Consiglio Nazionale delle Ricerche*.

* Electronic address: andrea.gauzzi@upmc.fr

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